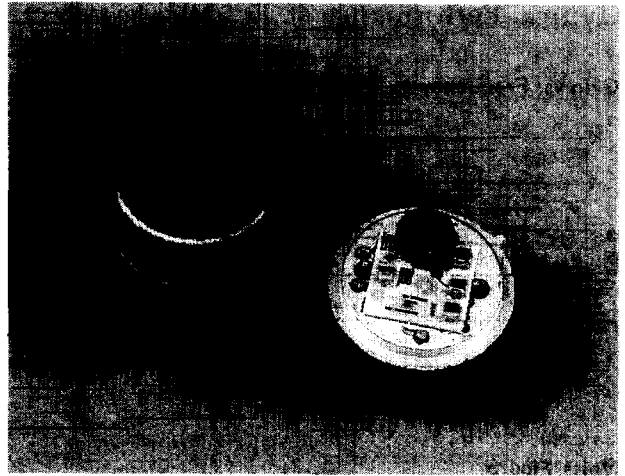




# A72 / SMA72

## 5 to 500 MHz TO-8 CASCADABLE AMPLIFIER

- ◆ AVAILABLE IN SURFACE MOUNT
- ◆ LOW POWER DRAIN: 31 mA (TYP.) @ +5 Vdc
- ◆ HIGH OUTPUT LEVEL WITH  
LOW Vcc: +12.5 dBm (TYP.) @ 5 Vdc
- ◆ HIGH THIRD ORDER I.P.: +28 dBm (TYP.)  
@ Vcc = +8 Vdc



### Specifications\*

Characteristics	Typical	Guaranteed	
		0° to 50°C	-54° to +85°C
Frequency (Min.)	2-700 MHz	5-500 MHz	5-500 MHz
Small Signal Gain (Min.)	15.0 dB	14.0 dB	13.5 dB
Gain Flatness (Max.)	±0.2 dB	±0.7 dB	±1.0 dB
Noise Figure (Max.)	3.3 dB	4.0 dB	4.5 dB
Power Output at 1 dB Compression (Min.)			
Vcc = 5 V	+12.5 dBm	+11.5 dBm	+11.0 dBm
Vcc = 8 V	+16.5 dBm	+15.5 dBm	+15.0 dBm
VSWR (Max.) Input/Output	<1.3:1	1.7:1	1.8 :1
DC Current (Max.) at 5 Volts			
Vcc = 5 V	31 mA	34 mA	36 mA
Vcc = 8 V	52 mA	56 mA	58 mA

\*Measured in a 50-ohm system at +5 Vdc unless otherwise specified.

#### Notes:

1. WJ-CA72 is a standard WJ-A72 installed in a miniature SMA connector housing and guaranteed over 0°C to 50°C temperature range.

### Typical Intermodulation Performance at 25°C

Second Order Harmonic Intercept Point.....	+42 dBm (Typ.), 5 V
	+39 dBm (Typ.), 8 V
Second Order Two Tone Intercept Point.....	+36 dBm (Typ.), 5 V
	+33 dBm (Typ.), 8 V
Third Order Two Tone Intercept Point.....	+26 dBm (Typ.), 5 V
	+28 dBm (Typ.), 8 V

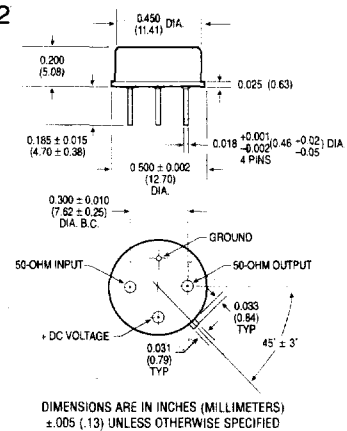
### Absolute Maximum Rating

Storage Temperature.....	-62° to +125°C
Maximum Case Temperature.....	125°C
Maximum DC Voltage.....	9 Volts
Maximum Continuous RF Input Power.....	+13 dBm
Maximum Short Term RF Input Power (1 Minute Max.).....	50 Milliwatts
Maximum Peak Power.....	0.5 Watt (3 µsec Max.)
"S" Series Burn-In Temperature (Case).....	+125°C

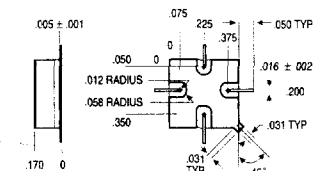
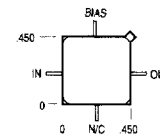
Weight approximately 2.0 grams (0.07 oz.)

### Outline Drawings

A72

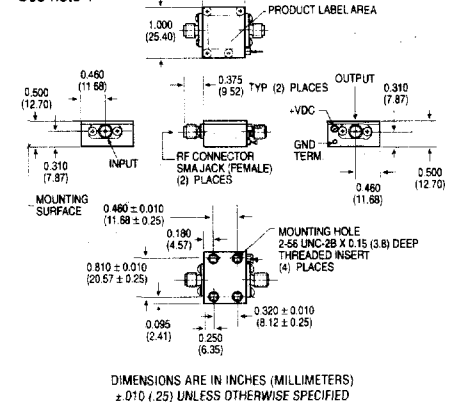


SMA72



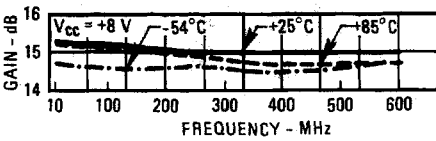
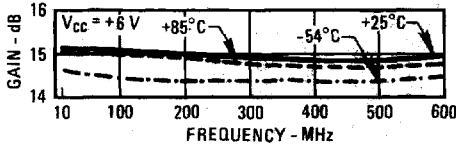
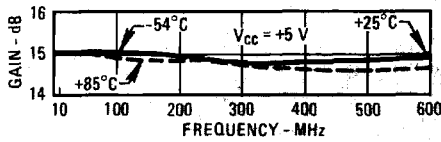
CA72

See note 1

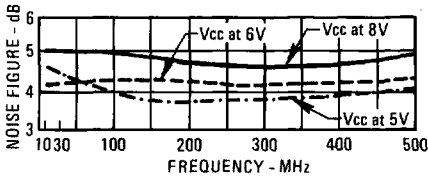


Typical Performance at 25°C

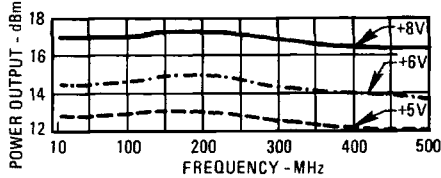
Gain



Noise Figure

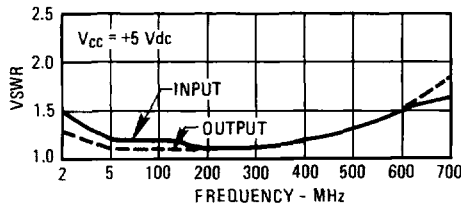


Power Output\*

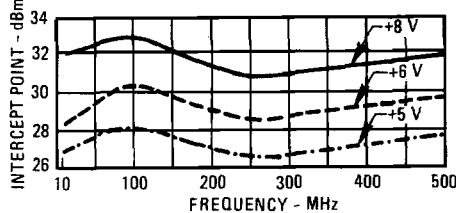


\* at 1 dB Gain Compression

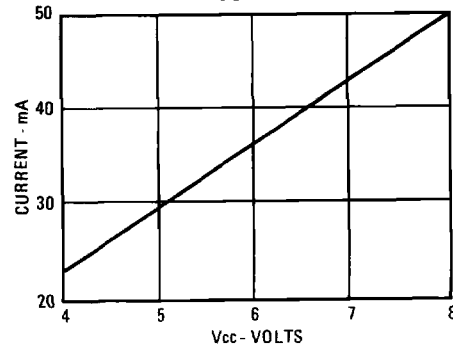
VSWR



3rd Order Two Tone Intercept Point



Current Drain vs. Vcc



Typical Automatic Test Data

Vcc = 8.0 V

Frequency MHz	VSWR IN	VSWR OUT	GAIN DB
1.0	2.0	2.4	12.6
2.0	1.5	1.6	14.7
5.0	1.2	1.2	15.2
10.0	1.1	1.1	15.3
50.0	1.0	1.0	15.3
100.0	1.0	1.1	15.3
200.0	1.1	1.1	15.3
300.0	1.1	1.1	15.3
400.0	1.2	1.1	15.4
500.0	1.2	1.0	15.6
600.0	1.3	1.1	15.8
700.0	1.4	1.3	16.0

Linear S-Parameters

Frequency MHz	S11		S21		S12		S22	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
1.0	.342	-50	4.265	-136	.076	45	.411	-173
2.0	.205	-74	5.432	-155	.097	26	.228	140
5.0	.081	-89	5.746	-171	.103	10	.089	116
10.0	.044	-96	5.794	-176	.104	5	.051	110
50.0	.017	163	5.849	172	.105	-3	.024	86
100.0	.023	94	5.824	163	.105	-9	.029	75
200.0	.037	68	5.796	145	.105	-18	.043	60
300.0	.057	49	5.815	128	.103	-27	.051	43
400.0	.087	17	5.892	111	.103	-36	.039	23
500.0	.109	-11	6.000	92	.100	-46	.009	0
600.0	.134	-46	6.194	72	.097	-57	.048	166
700.0	.157	-91	6.334	49	.090	-68	.142	140

Vcc = 5.0 V

Frequency MHz	VSWR IN	VSWR OUT	GAIN DB
1.0	2.1	2.4	12.3
2.0	1.5	1.6	14.5
5.0	1.2	1.2	15.0
10.0	1.1	1.1	15.0
50.0	1.0	1.0	15.1
100.0	1.0	1.0	15.1
200.0	1.1	1.0	15.0
300.0	1.1	1.0	15.0
400.0	1.1	1.0	15.2
500.0	1.2	1.1	15.2
600.0	1.2	1.2	15.4
700.0	1.3	1.5	15.5

Linear S-Parameters

Frequency MHz	S11		S21		S12		S22	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
1.0	.362	-51	4.115	-136	.077	45	.407	-174
2.0	.213	-70	5.293	-154	.099	26	.227	136
5.0	.082	-78	5.604	-171	.105	10	.086	104
10.0	.044	-77	5.651	-177	.106	5	.048	90
50.0	.003	98	5.707	172	.107	-3	.023	42
100.0	.019	67	5.674	163	.107	-8	.021	31
200.0	.025	36	5.648	145	.106	-17	.020	37
300.0	.041	39	5.647	127	.105	-25	.016	53
400.0	.064	7	5.738	109	.105	-34	.015	128
500.0	.076	-21	5.775	91	.103	-43	.049	145
600.0	.096	-56	5.889	70	.100	-53	.106	136
700.0	.119	-99	5.929	47	.095	-62	.195	118

Thermal Data: Vcc = 15 Vdc

Thermal Resistance  $\theta_{jC}$  ..... 140°C/W  
 Transistor Power Dissipation  $P_d$  ..... 0.126 W  
 Junction Temperature Rise Above Case  $T_{jC}$  ..... 18°C

